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(54) **OLED DISPLAY HAVING COLOR FILTERS
FOR IMPROVING CONTRAST**

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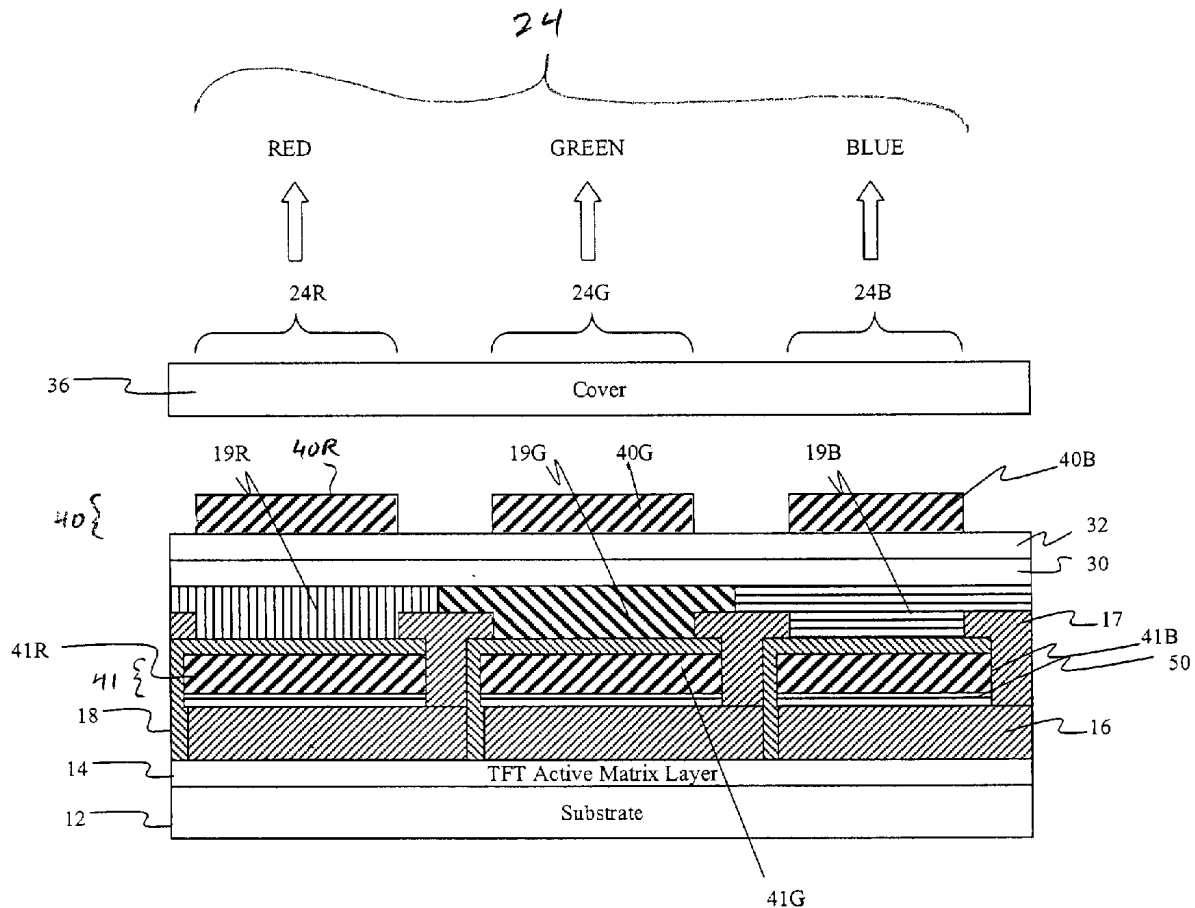
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(57) **ABSTRACT**

An OLED display device for displaying a color image, the display device being viewed from a front side includes a plurality of OLED elements including first color elements that emit a first color of light and second color elements that emit a second color of light different from the first color; a reflector located behind the OLED elements; and a corresponding plurality of filter elements aligned with the OLED elements, including first and second color filters for passing the first or second color of light emitted by the corresponding OLED element, and blocking other colors of light.



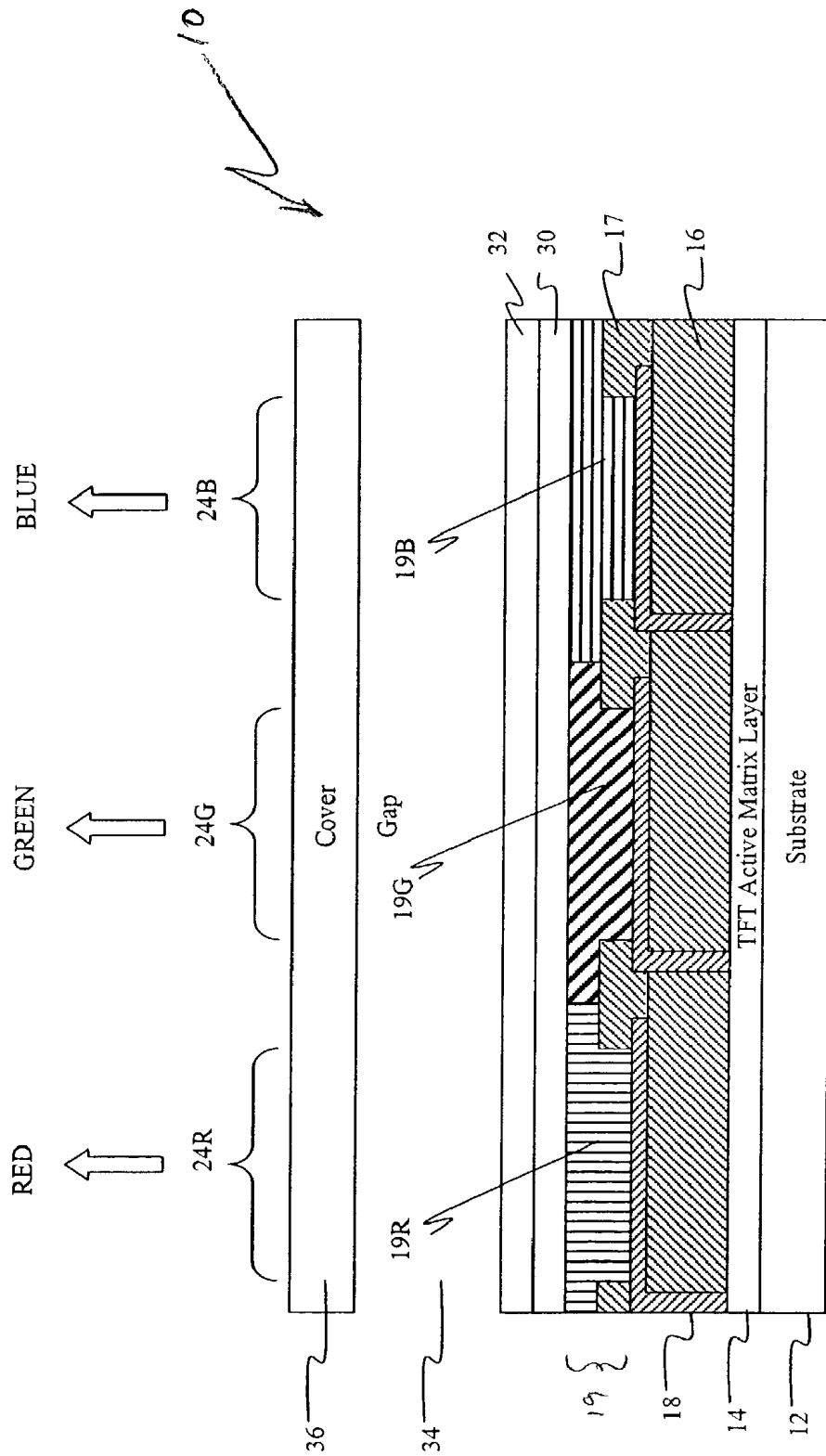


FIG. 1
(Prior Art)

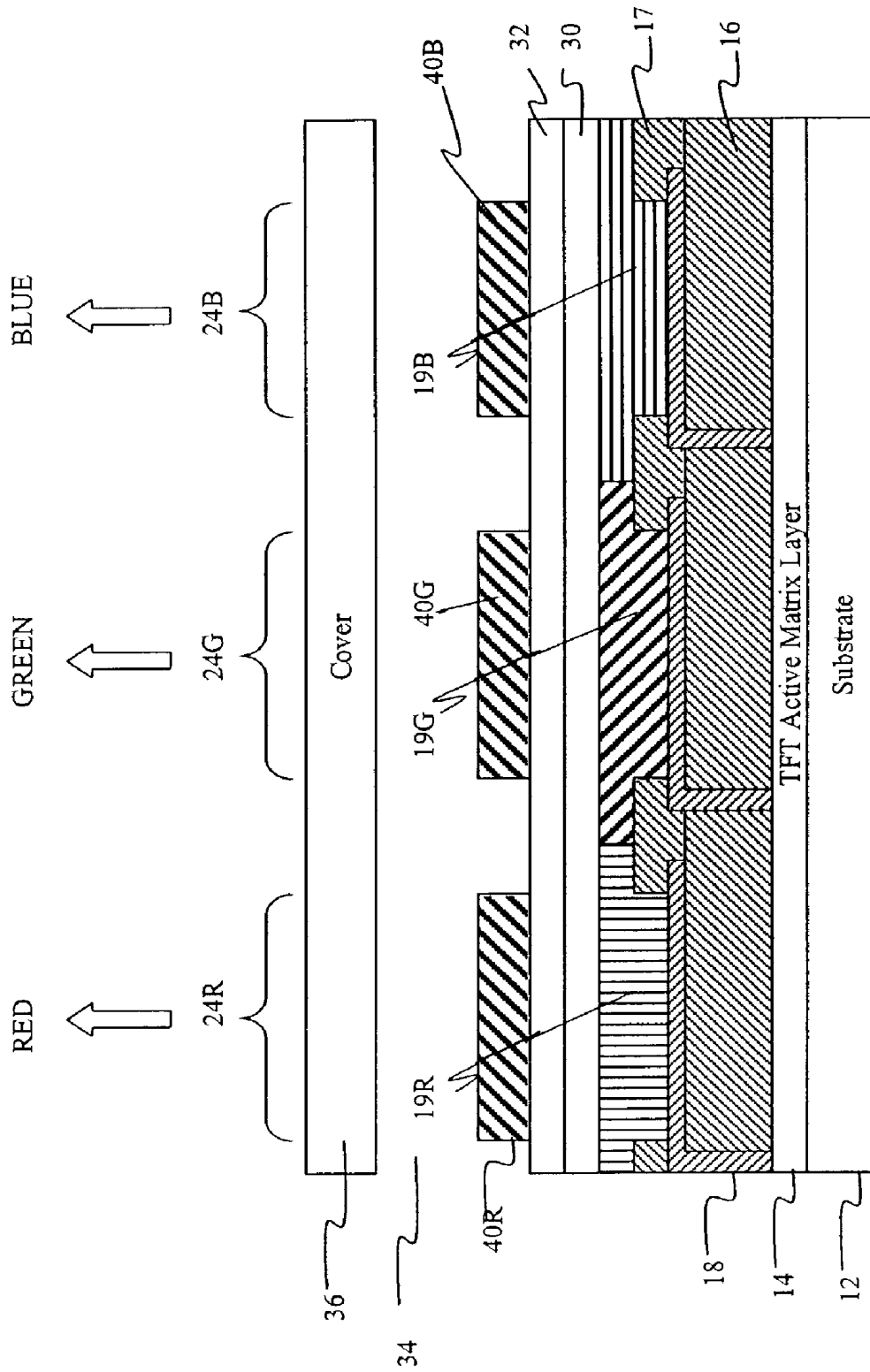
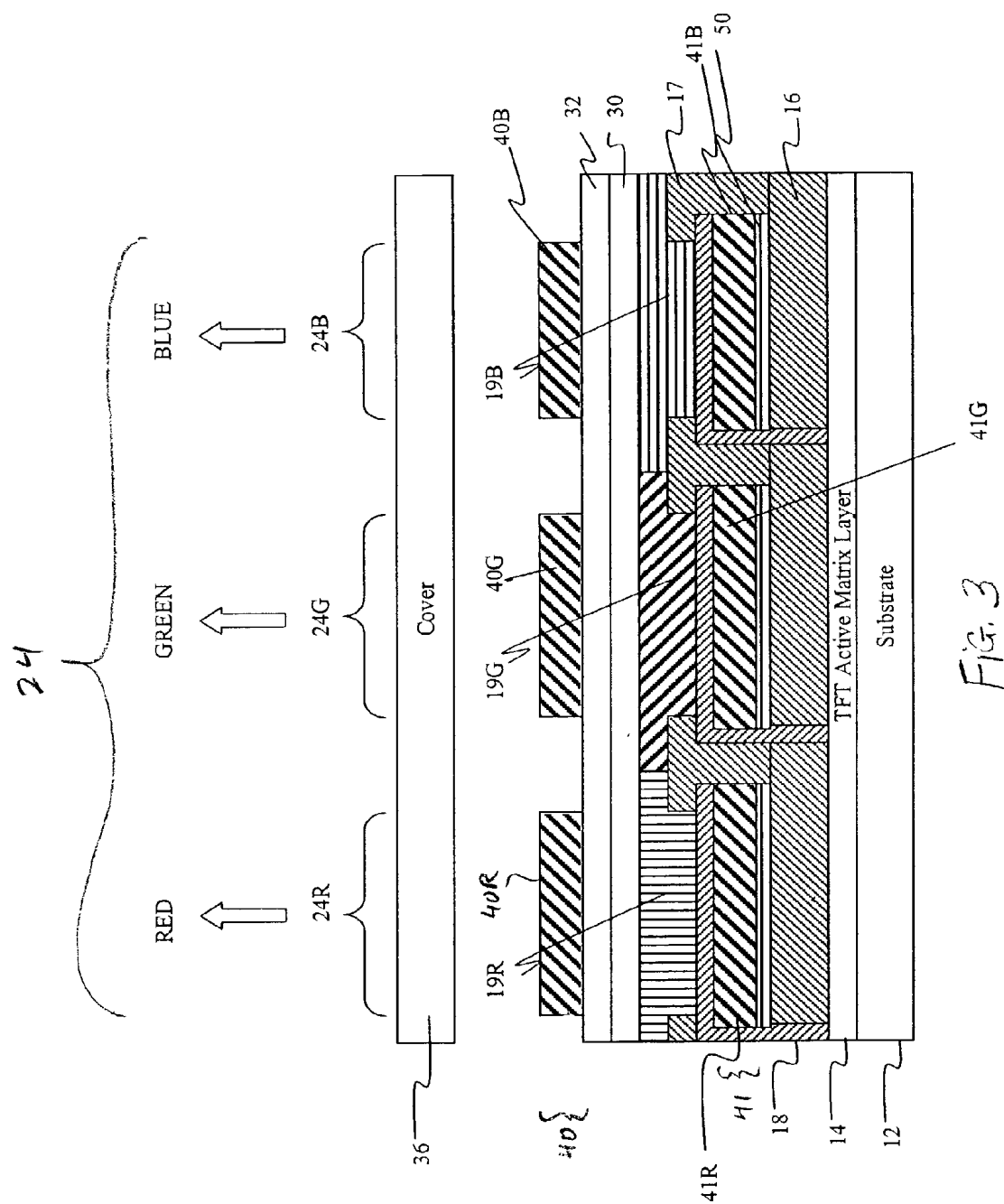


FIG. 2



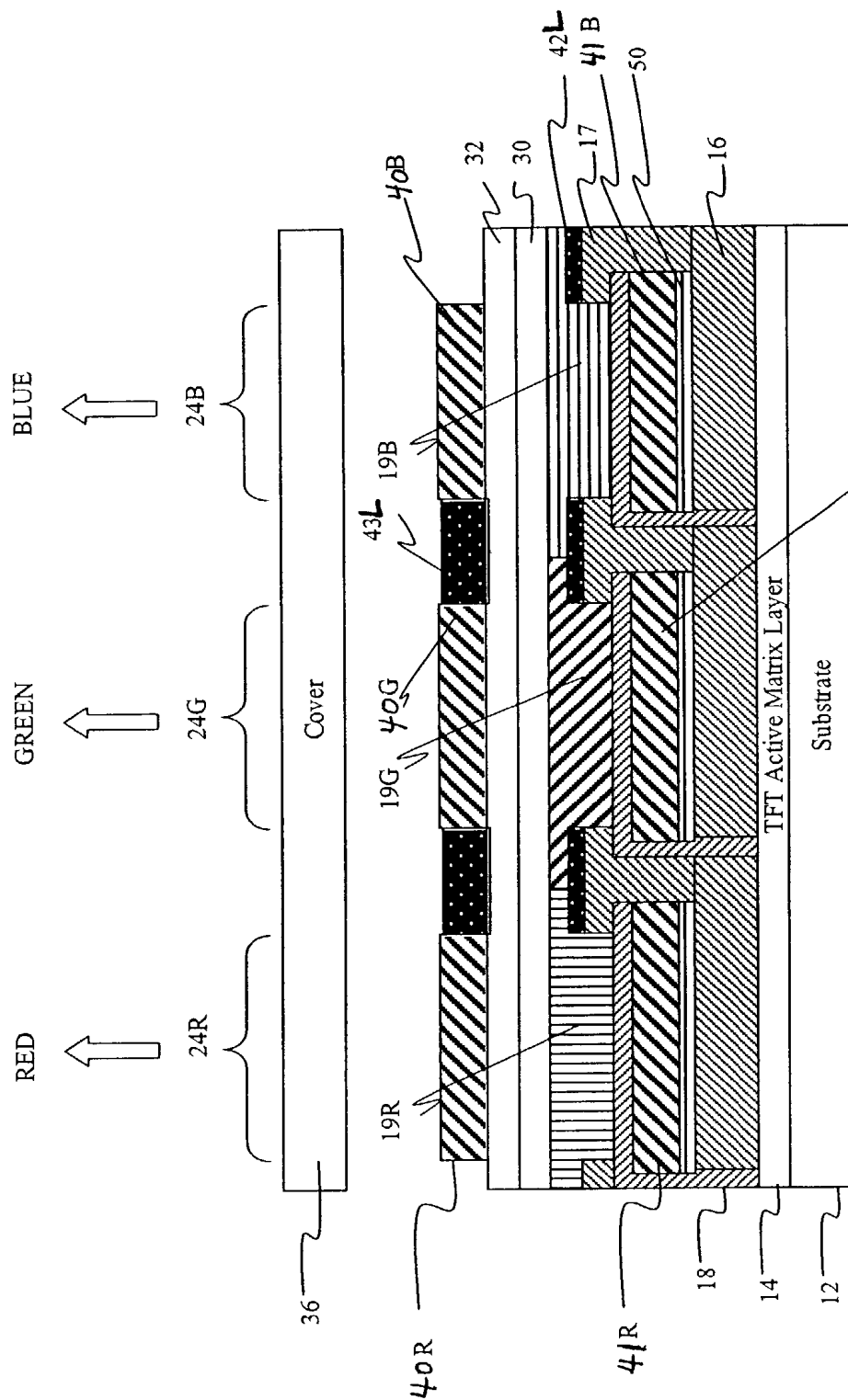


FIG. 4

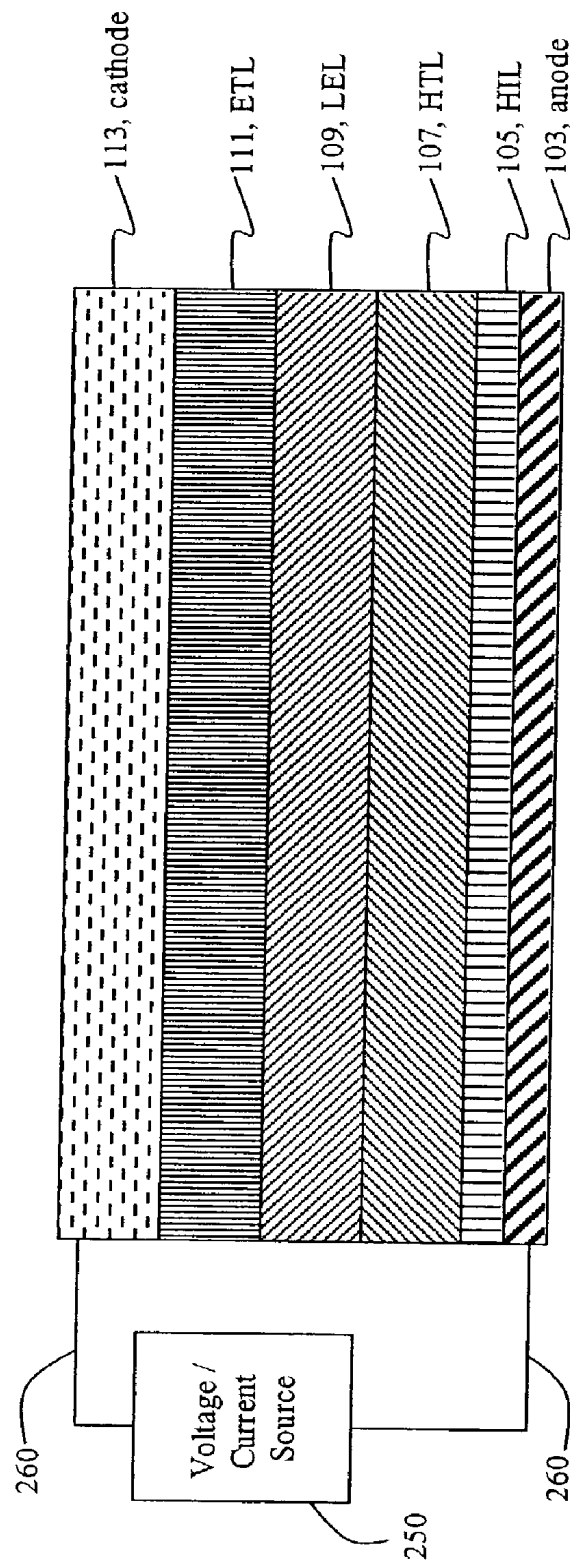


FIG. 5
(PRIOR ART)

OLED DISPLAY HAVING COLOR FILTERS FOR IMPROVING CONTRAST

FIELD OF THE INVENTION

[0001] The present invention relates to organic light emitting diode (OLED) displays, and more particularly, to OLED displays having improved contrast and color gamut.

BACKGROUND OF THE INVENTION

[0002] Organic light-emitting diode (OLED) display devices utilize a current passed through thin-film layers of organic materials to generate light. Electrodes located on either side of the organic layers provide current to the organic layers. The color of the light depends on the specific organic material and the light is Lambertian and emitted in every direction. A portion of the light is emitted directly toward the front of the display device: through a substrate (for a bottom emitter device) or an encapsulating cover (for a top emitter device). A similar portion of the light is emitted toward the back of the display device and may be either absorbed or reflected by a layer behind the organic layers. If the portion of light emitted toward the back is reflected, it can pass through the organic layers again and be emitted through the front of the display, thereby increasing the brightness of the display. If the portion of the light emitted toward the back is absorbed, it is absorbed and lost.

[0003] In viewing conditions that include ambient illumination, it is important that a display device have a high contrast to improve the viewability of the display. The contrast is a ratio between light emitted from the display device and the ambient light reflected from the display device. If the contrast is very low, it is difficult for a viewer to see the display light rather than the ambient light. If the contrast is high, the display light is readily seen in comparison to the ambient light.

[0004] If the light emitted toward the back of an OLED device is absorbed, so will ambient light that enters the device. Thus, the contrast of the display is improved at the cost of half of the emitted light from the display device. If the light emitted toward the back of an OLED device is reflected, little display device light is lost but the contrast is degraded since any ambient light that enters the device is reflected back out.

[0005] Various means are known in the art to address problems with contrast. For example, circular polarizers may be placed on the front of a display device to enhance the contrast. 3M sells a circular polarizing filter HNC37 which preferentially absorbs ambient light that passes twice through the filter rather than emitted light which passes once through the filter. Unfortunately, the polarizing filter still absorbs 60% of the emitted light, is expensive, and is exposed to the environment. Other means to provide absorbing layers by creating black layers, such as anodes or cathodes, are also known in the art. However, as described above, such an approach has the disadvantage of absorbing 50% of the emitted light.

[0006] There is a need therefore for an improved means to optimize the light output and the contrast in an OLED display device.

SUMMARY OF THE INVENTION

[0007] The need is met by providing an OLED display device for displaying a color image, the display device being

viewed from a front side includes a plurality of OLED elements that includes first color elements that emit a first color of light and second color elements that emit a second color of light different from the first color; a reflector located behind the OLED elements; and a corresponding plurality of filter elements aligned with the OLED elements, including first and second color filters for passing the first or second color of light emitted by the corresponding OLED element, and blocking other colors of light.

ADVANTAGES

[0008] The present invention has the advantage that it increases the contrast of an OLED display device without significantly decreasing the light output from the device.

BRIEF DESCRIPTION OF THE DRAWINGS

[0009] FIG. 1 illustrates a partial cross section of a prior art conventional top-emitting OLED display device;

[0010] FIG. 2 is a partial cross section of a display having color filter elements located above the light emitting elements according to one embodiment of the present invention;

[0011] FIG. 3 is a partial cross section of a display having color filter elements located above and below the light emitting elements according to an alternative embodiment of the present invention;

[0012] FIG. 4 is a partial cross section of a display having color filter elements and a black matrix according to a further alternative embodiment of the present invention; and

[0013] FIG. 5 is a cross sectional view of a typical OLED element known in the art that illustrates some of the various layers that can be used to construct an OLED element.

[0014] It will be understood that the figures are not to scale since the individual layers are too thin and the thickness differences of various layers too great to permit depiction to scale.

DETAILED DESCRIPTION OF THE INVENTION

[0015] The present invention is useful for both top-emitting OLED display devices (those that emit light through a cover placed above a substrate on which the OLED is constructed) and bottom-emitting OLED display devices (those that emit light through the substrate on which the OLED is constructed).

[0016] Referring to FIG. 1, a prior art top-emitting OLED display device 10 is shown with a substrate 12, and a thin-film transistor (TFT) active matrix layer 14 comprising an array of TFTs that provides power to OLED elements. A patterned first insulating layer 16 is provided over the TFT active matrix layer, and an array of first electrodes 18 are provided over insulating layer 16 and in electrical contact with the TFT active matrix layer. A patterned second insulating layer 17 is provided over the array of first electrodes 18 such that at least a portion of each of the first electrodes 18 is exposed.

[0017] Over the first electrodes and insulating layers are provided red, green, and blue-emitting organic electroluminescent (EL) elements, 19R, 19G, and 19B, respectively.

Herein, the collection of organic EL elements may also be referred to as the organic EL layer **19**. The light-emitting area is generally defined by the area of the first electrode **18** in contact with the organic EL elements. Over the organic EL layer **19** is provided a transparent, common second electrode **30** that has sufficient optical transparency to allow transmission of the generated red, green, and blue light. An optional second electrode protection layer **32** may be used to protect the electrode and underlying layers. Each first electrode in combination with its associated organic EL element and second electrode is herein referred to as an OLED element. A typical top-emitting OLED display device comprises an array of OLED elements wherein each OLED element emits red, green or blue. A gap **34**, generally filled with inert gas or a transmissive polymer material separates the electrode protection layer from an encapsulating cover **36**.

[0018] In operation, the thin-film transistors in TFT layer **14** allow current to flow between the first electrode **18**, each of which can be selectively addressed, and the common second electrode **30**. Holes and electrons recombine within the organic EL elements to emit light **24** R, G and B from the light emitting elements **19** R, G and B respectively.

[0019] Referring to **FIG. 2**, in a first embodiment of a top-emitting OLED display device having filter elements according to the present invention, the first electrodes **18** are reflective, or a reflective layer (not shown) is provided under the first electrodes. The display device includes a filter layer **40R**, **40G**, and **40B** provided over the light emitting elements. The filter layers **40** are the same, or nearly the same, color as the light emitting elements over which they are deposited. Suitable filter materials are used in the manufacture of charge-coupled imaging devices (CCDs) commercially available today and are deposited using conventional evaporation or sputtering means. These color filter arrays are conventionally used to filter ambient light that strikes an imaging device to render the image sensing sites color sensitive. The use of Color Filter Arrays is also known in OLED display devices and the color filter arrays are conventionally used to produce a colored display using white light emitting elements. For example, U.S. application publication Ser. No. **20,020,024,051 A1**, published Feb. 28, 2002, entitled "Light Emitting Device" describes such a design. Manufacturing is done with traditional masking means as is well known in the art and the materials (a separate material for each light emitter **19R**, **19G**, and **19B**) are deposited over the cathode protection layer **32**. Alternatively, the color filter layers can be provided on the inside or outside surface of cover **36**, preferably on the inside to provide protection for the filter layers.

[0020] In operation, current is passed via the electrodes **18** and **30** through the light emitting elements **19** causing light to be emitted both upward through second electrode **30** and downward toward the substrate. The light that is emitted through second electrode **30** passes through filter layer **40** and is emitted through the encapsulating cover **36**. Light that is emitted toward the substrate **12** is reflected from the first electrodes **18** and passes through the light emitters and the filter layer **40** and is emitted through the cover **36**. According to the present invention, the spectrum of the emitted light approximately matches that of the filter. Little light is lost and almost all of the light is emitted from the device, even the light that is reflected from the electrodes **18**. Preferably,

the spectral properties of the filter are selected so that >80% of the incident light generated by the pixel is transmitted.

[0021] Ambient light can enter the device through the cover **36** and only a portion of the ambient light is passed by the filter layer **40**. The spectrum for each of the filters, Red, Green, and Blue is different. If the spectrum passed by each of the color filters is considered to be about one third of the visible spectrum for each of the three colors, the light reflected from the display is only one third of the ambient light incident on the display, thereby improving the contrast of the display.

[0022] Referring to **FIG. 3**, in an alternative embodiment of a top-emitting OLED device of the present invention, the first electrode layer **18** is transparent. A reflector layer **50** is located between first insulating layer **16** and the transparent first electrode **18**. The reflector layer **50** can be for example, a patterned layer of a reflective metal including, but not limited to, silver, chromium, molybdenum or aluminum. Such a layer must be patterned so as to prevent shorting between first electrodes. A reflective dielectric stack as known in the art may also be used as reflector layer **50**. Because a dielectric stack is not conductive, there is less risk of shorting between first electrodes. Also, a dielectric stack mirror can be deposited as a continuous film over the first insulating layer, and vias for first electrode **18** can be patterned along with the first insulating layer. Alternatively, a dielectric stack mirror can serve the function of first insulator layer. By "reflective", it is meant that at least 50% of the incident light is reflected. Preferably, it is greater than 70%, and more preferably, greater than 90%. A filter layer **41R**, **41G**, and **41B** as described above is provided between the reflector layer **50** and the transparent first electrode **18**. Transparent electrodes are well known in the art and the application of reflective films is also well known. Alternatively, the insulating layer **16** itself may serve as a color filter if a reflective layer is provided underneath it.

[0023] It should be noted that the display device may include only filter layers **41** located below the light emitting elements, or filter elements **40** and **41** may be provided both above and below the light emitting elements (as shown in **FIG. 3**). In operation, both the reflected and directly emitted light will pass through the filter above the second electrode and be seen by a viewer. Ambient light outside the filter spectrum will be absorbed as described above. Since the filters are not perfect and do not absorb all of the appropriate light passing through them, the use of multiple filters can further improve the contrast of the display.

[0024] The filter layers **40** and **41** can also be trimming filters that are used to modify the spectrum of the emitters. By trimming filters, it is meant that the spectrum of light passed by the filter is narrower than the spectrum of light emitted by the OLED. Since some OLED materials do not have quite the desired emissive spectrum for a given display application, unwanted light emitted from such materials can be absorbed by suitable trimming filters designed for each color. This approach somewhat reduces the brightness of the display, but can be used to improve the color gamut of the display while improving the contrast of the display.

[0025] Color filter arrays can also be placed on the encapsulating cover **36**, either on the inside or outside surface of the cover. By providing the cover with a properly aligned array of filters, the light from each light emitter can be

suitably filtered. Preferably, the filter array is located on the inside of the cover, thereby reducing the environmental exposure of the filter elements.

[0026] In another embodiment, the present invention can be applied to a bottom-emitter OLED display device. In a bottom-emitter device, the filter elements can be located on either side of the substrate, behind the light emitting elements, or on a cathode protection layer, or on the encapsulating cover. The reflective layer is located behind the filter elements, for example on the inside of a reflective encapsulating cover.

[0027] In a typical OLED display device, the light emitting elements do not cover the entire substrate. It is known to provide a pattern of light absorbing material in the spaces between the light emitting elements. Such patterns of light absorbing material can enhance the contrast of the device with no loss of light output from the device. The degree of contrast improvement is dependent on the fill factor of the display. The lower the fill factor of the display the more the contrast is improved by use of such patterns of light absorbing material. Suitable materials for creating black layers are known in the art and can include, for example, carbon black. The present invention may be practiced together with such light absorbing patterns located above, beneath, or within the layers of the OLED device. Referring to FIG. 4, for example, a pattern of black absorbing material 42L may be placed above either the second insulating layer 17 or above the cathode sealing layer 32L or in conjunction with the color filters.

[0028] The same approach can be used for a bottom-emitting device. By locating a pattern of light absorbing material in, above, or beneath the portions of layers that do not obscure light emission, contrast can be improved.

[0029] An alternative to the use of black light absorbing material is to overlap the color filters in the regions between the light emitting elements to form a wide spectrum light absorbing pattern. For example, in regions where red and blue filter elements overlap all light will be effectively absorbed.

[0030] It may also be useful to include additional layers to provide compatibility between the filter materials and other layers of the OLED device, for example to promote adhesion of the filter material, to provide a smooth surface, or to protect the filter material. For example, silicon oxide layers are often used to meet these needs.

[0031] When provided, the protection layer 32 for top emitting display devices may comprise inorganic materials such as SiOx or SiNx, for example, as disclosed in JP 2001126864. Alternatively, the protection layer 32 may comprise organic materials such as polymers, including but not limited to, Teflon®, polyimides, and polymers disclosed in JP 11162634. Protection layer 32 may comprise multiple layers of organic or inorganic materials, or combinations thereof. Alternating inorganic and organic layers, for example, as disclosed in U.S. Pat. No. 6,268,295 issued Jul. 31, 2001 to Ohta et al., and WO 00/36665 by Graff et al., published Jun. 22, 2000, are useful as protection layer 32. In all cases, the protection layer 32 should have high optical transparency, preferably greater than 70% transmittance. For convenience, the combination of layers from the substrate through the optional protection layer is referred to herein as the OLED substrate.

[0032] The filtering materials 40 and 41 may be deposited in a pattern using photolithographic techniques known in the art. For example, light absorbing material may be coated as a liquid on the entire surface and exposed to radiation through a mask to polymerize portions of the coating. Portions of the material exposed to the radiation are cured and the remainder is washed away. Dry film photolithography may also be used. In addition, patterned thermal transfer can be used, for example, by coating filter material 40 and 41 onto a donor substrate, placing the donor substrate in contact or close proximity to the OLED substrate, and selectively heating the donor with a laser to cause transfer of the filtering material to the OLED substrate. The filtering material 40 and 41 may comprise a plurality of thinner layers deposited by sequential deposition of filter materials.

[0033] While transparent cover 36 is typically glass or plastic sheet, the cover can comprise materials that are deposited in a conformable manner over the surface of the materials deposited over the substrate, i.e., over OLED substrate with patterned filtering material 40 and 41. The same materials useful as protection layer 32 can be used as a transparent conformable cover (not shown).

[0034] This invention is advantageously practiced with both top-emitting and bottom-emitting OLED active matrix devices. This invention may be used in any OLED device including simple matrix or passive matrix devices.

[0035] General Device Architecture

[0036] The present invention can be employed in most OLED device configurations. These include very simple structures comprising a single anode and cathode to more complex devices, such as passive matrix displays comprised of orthogonal arrays of anodes and cathodes to form pixels, and active-matrix displays where each pixel is controlled independently, for example, with a thin film transistor (TFT).

[0037] There are numerous configurations of the organic layers wherein the present invention can be successfully practiced. A typical structure is shown in FIG. 5 and is comprised of an anode layer 103, a hole-injecting layer 105, a hole-transporting layer 107, a light-emitting layer 109, an electron-transporting layer 111, and a cathode layer 113. These layers are described in detail below. Note that the substrate may be located adjacent to the cathode, or the substrate may actually constitute the anode or cathode. The organic layers between the anode and cathode are conveniently referred to as the organic EL element. The total combined thickness of the organic layers is preferably less than 500 nm.

[0038] Substrate

[0039] The OLED device of this invention is typically provided over a supporting substrate 12, which as previously described, may also comprise other layers such as TFT electronics and insulating layers. The electrode provided over the substrate is conveniently referred to as the bottom electrode. Conventionally, the bottom electrode is the anode, but this invention is not limited to that configuration. The substrate can either be light transmissive or opaque, depending on the intended direction of light emission. The light transmissive property is desirable for viewing the EL emission through the substrate. Transparent glass or plastic is commonly employed in such cases. For applications where

the EL emission is viewed through the top electrode, the transmissive characteristic of the bottom support is immaterial, and therefore can be light transmissive, light absorbing or light reflective. Substrates for use in this case include, but are not limited to, glass, plastic, semiconductor materials, silicon, ceramics, and circuit board materials. Of course it is necessary to provide in these device configurations a light-transparent top electrode.

[0040] Anode

[0041] When EL emission is viewed through anode **103**, the anode should be transparent or substantially transparent to the emission of interest. Common transparent anode materials used in this invention are indium-tin oxide (ITO), indium-zinc oxide (IZO) and tin oxide, but other metal oxides can work including, but not limited to, aluminum- or indium-doped zinc oxide, magnesium-indium oxide, and nickel-tungsten oxide. In addition to these oxides, metal nitrides, such as gallium nitride, and metal selenides, such as zinc selenide, and metal sulfides, such as zinc sulfide, can be used as the anode. For applications where the anode is reflective, conductors may include, but are not limited to, gold, iridium, molybdenum, palladium, and platinum. Typical anode materials, transmissive or otherwise, have a work function of 4.1 eV or greater. Desired anode materials are commonly deposited by any suitable means such as evaporation, sputtering, chemical vapor deposition, or electrochemical means. Anodes can be patterned using well-known photolithographic processes.

[0042] Hole-Injecting Layer (HIL)

[0043] It is often useful to provide a hole-injecting layer **105** between anode **103** and hole-transporting layer **107**. The hole-injecting material can serve to improve the film formation property of subsequent organic layers and to facilitate injection of holes into the hole-transporting layer. Suitable materials for use in the hole-injecting layer include, but are not limited to, porphyrinic compounds as described in U.S. Pat. No. 4,720,432, and plasma-deposited fluorocarbon polymers as described in U.S. Pat. No. 6,208,075. Alternative hole-injecting materials reportedly useful in organic EL devices are described in EP 0 891 121 A1 and EP 1 029 909 A1.

[0044] Hole-Transporting Layer (HTL)

[0045] The hole-transporting layer **107** contains at least one hole-transporting compound such as an aromatic tertiary amine, where the latter is understood to be a compound containing at least one trivalent nitrogen atom that is bonded only to carbon atoms, at least one of which is a member of an aromatic ring. In one form the aromatic tertiary amine can be an arylamine, such as a monoarylamine, diarylamine, triarylamine, or a polymeric arylamine. Exemplary monomeric triarylaminos are illustrated by Klupfel et al. U.S. Pat. 3,180,730. Other suitable triarylaminos substituted with one or more vinyl radicals and/or comprising at least one active hydrogen containing group are disclosed by Brantley et al. in U.S. Pat. Nos. 3,567,450 and 3,658,520.

[0046] A more preferred class of aromatic tertiary amines are those which include at least two aromatic tertiary amine moieties as described in U.S. Pat. Nos. 4,720,432 and 5,061,569. The hole-transporting layer can be formed of a single or a mixture of aromatic tertiary amine compounds. Illustrative of useful aromatic tertiary amines are the following:

- [0047]** 1,1-Bis(4-di-p-tolylaminophenyl)cyclohexane
- [0048]** 1,1-Bis(4-di-p-tolylaminophenyl)-4-phenylcyclohexane
- [0049]** 4,4'-Bis(diphenylamino)quadriphenyl
- [0050]** Bis(4-dimethylamino-2-methylphenyl)-phenylmethane
- [0051]** N,N,N-Tri(p-tolyl)amine
- [0052]** 4-(di-p-tolylamino)-4'-[4(di-p-tolylamino)-styryl]stilbene
- [0053]** N,N,N',N'-Tetra-p-tolyl-4-4'-diaminobiphenyl
- [0054]** N,N,N',N'-Tetraphenyl-4,4'-diaminobiphenyl
- [0055]** N,N,N',N'-tetra-1-naphthyl-4,4'-diaminobiphenyl
- [0056]** N,N,N',N'-tetra-2-naphthyl-4,4'-diaminobiphenyl
- [0057]** N-Phenylcarbazole
- [0058]** 4,4'-Bis[N-(1-naphthyl)-N-phenylamino]biphenyl
- [0059]** 4,4'-Bis[N-(1-naphthyl)-N-(2-naphthyl)amino]biphenyl
- [0060]** 4,4''-Bis[N-(1-naphthyl)-N-phenylamino]p-terphenyl
- [0061]** 4,4'-Bis[N-(2-naphthyl)-N-phenylamino]biphenyl
- [0062]** 4,4'-Bis[N-(3-acenaphthenyl)-N-phenylamino]biphenyl
- [0063]** 1,5-Bis[N-(1-naphthyl)-N-phenylamino]naphthalene
- [0064]** 4,4'-Bis[N-(9-anthryl)-N-phenylamino]biphenyl
- [0065]** 4,4''-Bis[N-(1-anthryl)-N-phenylamino]p-terphenyl
- [0066]** 4,4'-Bis[N-(2-phenanthryl)-N-phenylamino]biphenyl
- [0067]** 4,4'-Bis[N-(8-fluoranthryl)-N-phenylamino]biphenyl
- [0068]** 4,4'-Bis[N-(2-pyrenyl)-N-phenylamino]biphenyl
- [0069]** 4,4'-Bis[N-(2-naphthacenyl)-N-phenylamino]biphenyl
- [0070]** 4,4'-Bis[N-(2-perylenyl)-N-phenylamino]biphenyl
- [0071]** 4,4'-Bis[N-(1-coronenyl)-N-phenylamino]biphenyl
- [0072]** 2,6-Bis(di-p-tolylamino)naphthalene
- [0073]** 2,6-Bis[di-(1-naphthyl)amino]naphthalene
- [0074]** 2,6-Bis[N-(1-naphthyl)-N-(2-naphthyl)amino]naphthalene

[0075] N,N,N',N'-Tetra(2-naphthyl)-4,4''-diamino-p-terphenyl

[0076] 4,4'-Bis{N-phenyl-N-[4-(1-naphthyl)-phenyl]amino}biphenyl

[0077] 4,4'-Bis[N-phenyl-N-(2-pyrenyl)amino]biphenyl

[0078] 2,6-Bis[N,N-di(2-naphthyl)amine]fluorene

[0079] 1,5-Bis[N-(1-naphthyl)-N-phenylamino]naphthalene

[0080] Another class of useful hole-transporting materials includes polycyclic aromatic compounds as described in EP 1 009 041. In addition, polymeric hole-transporting materials can be used such as poly(N-vinylcarbazole) (PVK), polythiophenes, polypyrrole, polyaniline, and copolymers such as poly(3,4-ethylenedioxythiophene)/poly(4-styrenesulfonate) also called PEDOT/PSS.

[0081] Light-Emitting Layer (LEL)

[0082] As more fully described in U.S. Pat. Nos. 4,769,292 and 5,935,721, the light-emitting layer (LEL) 109 of the organic EL element includes a luminescent or fluorescent material where electroluminescence is produced as a result of electron-hole pair recombination in this region. The light-emitting layer can be comprised of a single material, but more commonly consists of a host material doped with a guest compound or compounds where light emission comes primarily from the dopant and can be of any color. The host materials in the light-emitting layer can be an electron-transporting material, as defined below, a hole-transporting material, as defined above, or another material or combination of materials that support hole-electron recombination. The dopant is usually chosen from highly fluorescent dyes, but phosphorescent compounds, e.g., transition metal complexes as described in WO 98/55561, WO 00/18851, WO 00/57676, and WO 00/70655 are also useful. Dopants are typically coated as 0.01 to 10% by weight into the host material. Polymeric materials such as polyfluorenes and polyvinylarylenes (e.g., poly(p-phenylenevinylene), PPV) can also be used as the host material. In this case, small molecule dopants can be molecularly dispersed into the polymeric host, or the dopant could be added by copolymerizing a minor constituent into the host polymer.

[0083] An important relationship for choosing a dye as a dopant is a comparison of the bandgap potential which is defined as the energy difference between the highest occupied molecular orbital and the lowest unoccupied molecular orbital of the molecule. For efficient energy transfer from the host to the dopant molecule, a necessary condition is that the band gap of the dopant is smaller than that of the host material.

[0084] Host and emitting molecules known to be of use include, but are not limited to, those disclosed in U.S. Pat. Nos. 4,769,292; 5,141,671; 5,150,006; 5,151,629; 5,405,709; 5,484,922; 5,593,788; 5,645,948; 5,683,823; 5,755,999; 5,928,802; 5,935,720; 5,935,721; and 6,020,078.

[0085] Metal complexes of 8-hydroxyquinoline(oxine) and similar derivatives constitute one class of useful host compounds capable of supporting electroluminescence. Illustrative of useful chelated oxinoid compounds are the following:

[0086] CO-1: Aluminum trisoxine[alias, tris(8-quinolinolato)aluminum(III)]

[0087] CO-2: Magnesium bisoxine[alias, bis(8-quinolinolato)magnesium(II)]

[0088] CO-3: Bis[benzo{f}-8-quinolinolato]zinc (II)

[0089] CO-4: Bis(2-methyl-8-quinolinolato)aluminum(III)- μ -oxo-bis(2-methyl-8-quinolinolato)aluminum(III)

[0090] CO-5: Indium trisoxine[alias, tris(8-quinolinolato)indium]

[0091] CO-6: Aluminum tris(5-methyloxine)[alias, tris(5-methyl-8-quinolinolato)aluminum(III)]

[0092] CO-7: Lithium oxine[alias, (8-quinolinolato)lithium(I)]

[0093] CO-8: Gallium oxine[alias, tris(8-quinolinolato)gallium(III)]

[0094] CO-9: Zirconium oxine[alias, tetra(8-quinolinolato)zirconium(IV)]

[0095] Other classes of useful host materials include, but are not limited to: derivatives of anthracene, such as 9,10-di-(2-naphthyl)anthracene and derivatives thereof, distyrylarylene derivatives as described in U.S. Pat. No. 5,121,029, and benzazole derivatives, for example, 2, 2', 2''-(1,3,5-phenylene)tris[1-phenyl-1H-benzimidazole].

[0096] Useful fluorescent dopants include, but are not limited to, derivatives of anthracene, tetracene, xanthene, perylene, rubrene, coumarin, rhodamine, quinacridone, dicyanomethylenepyrans compounds, thiopyran compounds, polymethine compounds, pyrilium and thiapyrilium compounds, fluorene derivatives, perfluoranthene derivatives and carbostyryl compounds.

[0097] Electron-Transporting Layer (ETL)

[0098] Preferred thin film-forming materials for use in forming the electron-transporting layer 111 of the organic EL elements of this invention are metal chelated oxinoid compounds, including chelates of oxine itself (also commonly referred to as 8-quinolinol or 8-hydroxyquinoline). Such compounds help to inject and transport electrons, exhibit high levels of performance, and are readily fabricated in the form of thin films. Exemplary oxinoid compounds were listed previously.

[0099] Other electron-transporting materials include various butadiene derivatives as disclosed in U.S. Pat. No. 4,356,429 and various heterocyclic optical brighteners as described in U.S. Pat. 4,539,507. Benzazoles and triazines are also useful electron-transporting materials.

[0100] In some instances, layers 111 and 109 can optionally be collapsed into a single layer that serves the function of supporting both light emission and electron transport. These layers can be collapsed in both small molecule OLED systems and in polymeric OLED systems. For example, in polymeric systems, it is common to employ a hole-transporting layer such as PEDOT-PSS with a polymeric light-emitting layer such as PPV. In this system, PPV serves the function of supporting both light emission and electron transport.

[0101] Cathode

[0102] When light emission is viewed solely through the anode, the cathode **113** used in this invention can be comprised of nearly any conductive material. Desirable materials have good film-forming properties to ensure good contact with the underlying organic layer, promote electron injection at low voltage, and have good stability. Useful cathode materials often contain a low work function metal (<4.0 eV) or metal alloy. One preferred cathode material is comprised of a Mg:Ag alloy wherein the percentage of silver is in the range of 1 to 20%, as described in U.S. Pat. No. 4,885,221. Another suitable class of cathode materials includes bilayers comprising a thin electron-injection layer (EIL) in contact with the organic layer (e.g., ETL) which is capped with a thicker layer of a conductive metal. Here, the EIL preferably includes a low work function metal or metal salt, and if so, the thicker capping layer does not need to have a low work function. One such cathode is comprised of a thin layer of LiF followed by a thicker layer of Al as described in U.S. Pat. No. 5,677,572. Other useful cathode material sets include, but are not limited to, those disclosed in U.S. Pat. Nos. 5,059,861; 5,059,862, and 6,140,763.

[0103] When light emission is viewed through the cathode, the cathode must be transparent or nearly transparent. For such applications, metals must be thin or one must use transparent conductive oxides, or a combination of these materials. Optically transparent cathodes have been described in more detail in U.S. Pat. No. 4,885,211, U.S. Pat. No. 5,247,190, JP 3,234,963, U.S. Pat. No. 5,703,436, U.S. Pat. No. 5,608,287, U.S. Pat. No. 5,837,391, U.S. Pat. No. 5,677,572, U.S. Pat. No. 5,776,622, U.S. Pat. No. 5,776,623, U.S. Pat. No. 5,714,838, U.S. Pat. No. 5,969,474, U.S. Pat. No. 5,739,545, U.S. Pat. No. 5,981,306, U.S. Pat. No. 6,137,223, U.S. Pat. No. 6,140,763, U.S. Pat. No. 6,172,459, EP 1 076 368, and U.S. Pat. No. 6,278,236. Cathode materials are typically deposited by evaporation, sputtering, or chemical vapor deposition. When needed, patterning can be achieved through many well known methods including, but not limited to, through-mask deposition, integral shadow masking as described in U.S. Pat. No. 5,276,380 and EP 0 732 868, laser ablation, and selective chemical vapor deposition.

[0104] Deposition of Organic Layers

[0105] The organic materials mentioned above are suitably deposited through a vapor-phase method such as sublimation, but can be deposited from a fluid, for example, from a solvent with an optional binder to improve film formation. If the material is a polymer, solvent deposition is useful but other methods can be used, such as sputtering or thermal transfer from a donor sheet. The material to be deposited by sublimation can be vaporized from a sublimator "boat" often comprised of a tantalum material, e.g., as described in U.S. Pat. No. 6,237,529, or can be first coated onto a donor sheet and then sublimed in closer proximity to the substrate. Layers with a mixture of materials can utilize separate sublimator boats or the materials can be pre-mixed and coated from a single boat or donor sheet. Patterned deposition can be achieved using shadow masks, integral shadow masks (U.S. Pat. No. 5,294,870), spatially-defined thermal dye transfer from a donor sheet (U.S. Pat. Nos. 5,851,709 and 6,066,357) and inkjet method (U.S. Pat. No. 6,066,357).

[0106] Encapsulation

[0107] Most OLED devices are sensitive to moisture or oxygen, or both, so they are commonly sealed in an inert atmosphere such as nitrogen or argon, along with a desiccant such as alumina, bauxite, calcium sulfate, clays, silica gel, zeolites, alkaline metal oxides, alkaline earth metal oxides, sulfates, or metal halides and perchlorates. Methods for encapsulation and desiccation include, but are not limited to, those described in U.S. Pat. No. 6,226,890 issued May 8, 2001 to Boroson et al. In addition, barrier layers such as SiO_x, Teflon, and alternating inorganic/polymeric layers are known in the art for encapsulation.

[0108] Optical Optimization

[0109] OLED devices of this invention can employ various well-known optical effects in order to enhance its properties if desired. This includes optimizing layer thicknesses to yield maximum light transmission, providing dielectric mirror structures, replacing reflective electrodes with light-absorbing electrodes, providing anti glare or anti-reflection coatings over the display, providing a polarizing medium over the display, or providing colored, neutral density, or color conversion filters over the display. Filters, polarizers, and anti-glare or anti-reflection coatings may be specifically provided over the cover or as part of the cover.

[0110] The invention has been described in detail with particular reference to certain preferred embodiments thereof, but it will be understood that variations and modifications can be effected within the spirit and scope of the invention.

PARTS LIST

- [0111] 10** top-emitting OLED device
- [0112] 12** substrate
- [0113] 14** TFT active matrix layer
- [0114] 16** first insulating planarization layer
- [0115] 17** second insulating layer
- [0116] 18** first electrode
- [0117] 19** organic EL layer
- [0118] 19B** blue-emitting organic EL element
- [0119] 19G** green-emitting organic EL element
- [0120] 19R** red-emitting organic EL element
- [0121] 24** emitted light
- [0122] 24B** blue emitted light
- [0123] 24G** green emitted light
- [0124] 24R** red emitted light
- [0125] 30** transparent second electrode
- [0126] 32** cathode protection layer
- [0127] 34** gap
- [0128] 36** encapsulating cover
- [0129] 40** filter element layer
- [0130] 40R** red filter element
- [0131] 40G** green filter element

- [0132] 40B blue filter element
- [0133] 41 filter element layer
- [0134] 41R red filter element
- [0135] 41G green filter element
- [0136] 41B blue filter element
- [0137] 42L patterned light absorbing layer
- [0138] 43L patterned light absorbing layer
- [0139] 50 reflector layer
- [0140] 103 anode layer
- [0141] 105 hole-injecting layer
- [0142] 107 hole-transporting layer
- [0143] 109 light-emitting layer
- [0144] 111 electron-transporting layer
- [0145] 113 cathode layer
- [0146] 250 voltage/current source
- [0147] 260 conductive wiring

What is claimed is:

1. An OLED display device for displaying a color image, the display device being viewed from a front side, comprising:

- a) a plurality of OLED elements including first color elements that emit a first color of light and second color elements that emit a second color of light different from the first color;
- b) a reflector located behind the OLED elements; and
- c) a corresponding plurality of filter elements aligned with the OLED elements, including first and second color filters for passing the first or second color of light emitted by the corresponding OLED element, and blocking other colors of light.

2. The display device claimed in claim 1, wherein the colors of light include red, green, and blue.

3. The display device claimed in claim 1, wherein the OLED display device is a top emitting device.

4. The display device claimed in claim 1, wherein the OLED display device is a bottom emitting device.

5. The display device claimed in claim 1, wherein the filter elements are located behind the OLED elements between the OLED elements and the reflector.

6. The display device claimed in claim 1, wherein the filter elements are located in front of the OLED elements.

7. The display device claimed in claim 6, further including a second corresponding plurality of filter elements located behind the OLED elements between the OLED elements and the reflector.

8. The display device claimed in claim 3, further comprising an encapsulating cover and wherein the color filter elements are located on the encapsulating cover.

9. The display device claimed in claim 8, wherein the color filter elements are located on the inside of the cover.

10. The display device claimed in claim 8, wherein the color filter elements are located on the outside of the cover.

11. The display device claimed in claim 4, further comprising a substrate and wherein the color filter elements are located on the substrate.

12. The display device claimed in claim 11, wherein the color filter elements are located on the inside of the substrate.

13. The display device claimed in claim 11, wherein the color filter elements are located on the outside of the substrate.

14. The display device claimed in claim 1, further comprising a black matrix surrounding the color filter elements.

15. The display device claimed in claim 14, wherein the black matrix is located behind the OLED elements between the OLED elements and the reflector.

16. The display device claimed in claim 14, wherein the black matrix is located in front of the OLED elements.

17. The display device claimed in claim 2, wherein the filter elements are trimming filters.

18. The display device claimed in claim 1, wherein the color filter elements partially overlap to provide a black matrix.

19. The display device claimed in claim 1, further comprising a protective layer is located adjacent to the color filter elements.

20. The display device claimed in claim 1, wherein the protective layer is a silicon oxide.

* * * * *

专利名称(译)	Oled显示器具有用于改善对比度的滤色器		
公开(公告)号	US20030230972A1	公开(公告)日	2003-12-18
申请号	US10/171277	申请日	2002-06-12
[标]申请(专利权)人(译)	伊斯曼柯达公司		
申请(专利权)人(译)	伊士曼柯达公司		
当前申请(专利权)人(译)	全球OLED科技有限责任公司		
[标]发明人	COK RONALD S		
发明人	COK, RONALD S.		
IPC分类号	H01L51/50 H01L27/32 H01L51/00 H01L51/30 H01L51/52 H05B33/12 H05B33/22 H05B33/00		
CPC分类号	H01L27/3211 H01L27/322 H01L27/3244 H01L51/005 H01L51/0052 H01L2251/5315 H01L51/0077 H01L51/0081 H01L51/5271 H01L51/5281 H01L51/5284 H01L51/0059		
其他公开文献	US6911772		
外部链接	Espacenet USPTO		

摘要(译)

一种用于显示彩色图像的OLED显示装置，该显示装置从正面观察，包括多个OLED元件，所述多个OLED元件包括发射第一颜色光的第一颜色元件和发射不同于第一颜色光的第二颜色元件的第二颜色元件。第一种颜色;位于OLED元件后面的反射器;相应的多个滤光元件与OLED元件对准，包括第一和第二滤色器，用于使相应的OLED元件发出的第一或第二颜色的光通过，并阻挡其它颜色的光。

